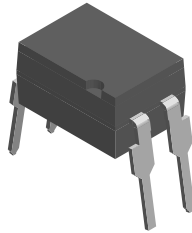
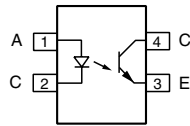




Optocoupler, Phototransistor Output, High Reliability, 5300 V_{RMS}



1179060



DESCRIPTION

The SFH615XXX features a large assortment of current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm lead spacing. Creepage and clearance distances of > 8 mm are achieved with option 6. This version complies with 60950 (DIN VDE 0805) for reinforced insulation up to operation voltage of 400 V_{RMS} or DC.

FEATURES

- Low CTR degradation
- Good CTR linearity depending on forward current
- Isolation test voltage, 5300 V_{RMS}
- High collector emitter voltage, V_{CEO} = 70 V
- Low saturation voltage
- Fast switching times
- Temperature stable
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode interference immunity (unconnected base)
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS COMPLIANT

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 pending available with option 1
- BSI IEC 60950; IEC 60065

ORDER INFORMATION	
PART	REMARKS
SFH615AA	CTR 50 to 600 %, DIP-4
SFH615AB	CTR 80 to 260 %, DIP-4
SFH615ABL	CTR 200 to 600 %, DIP-4
SFH615ABM	CTR 200 to 400 %, DIP-4
SFH615AGB	CTR 100 to 600 %, DIP-4
SFH615AGR	CTR 100 to 300 %, DIP-4
SFH615AY	CTR 50 to 150 %, DIP-4
SFH615AA-X006	CTR 50 to 600 %, DIP-4 400 mil (option 6)
SFH615AA-X007	CTR 50 to 600 %, SMD-4 (option 7)
SFH615ABM-X006	CTR 200 to 400 %, DIP-4 400 mil (option 6)
SFH615ABM-X007	CTR 200 to 400 %, SMD-4 (option 7)
SFH615AGB-X006	CTR 100 to 600 %, DIP-4 400 mil (option 6)
SFH615AGB-X009	CTR 100 to 600 %, SMD-4 (option 9)
SFH615AGR-X006	CTR 100 to 300 %, DIP-4 400 mil (option 6)
SFH615AGR-X007	CTR 100 to 300 %, SMD-4 (option 7)
SFH615AY-X006	CTR 50 to 150 %, DIP-4 400 mil (option 6)
SFH615AY-X008	CTR 50 to 150 %, SMD-4 (option 8)
SFH615AY-X009	CTR 50 to 150 %, SMD-4 (option 9)

Note

For additional information on the available options refer to option information.

SFH615AA/AGB/AGR/ABM/ABL/AY/AB



Vishay Semiconductors Optocoupler, Phototransistor Output,
High Reliability, 5300 V_{RMS}

ABSOLUTE MAXIMUM RATINGS (1)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V _R	6.0	V
DC forward current		I _F	60	mA
Surge forward current	t _p ≤ 10 ms	I _{FSM}	2.5	A
Power dissipation		P _{diss}	100	mW
OUTPUT				
Collector emitter voltage		V _{CE}	70	V
Emitter collector voltage		V _{EC}	7.0	V
Collector current		I _C	50	mA
	t _p ≤ 10 ms	I _C	100	mA
Total power dissipation		P _{diss}	150	mW
COUPLER				
Isolation test voltage between emitter and detector, refer to climate DIN 40046, part 2, Nov. 74		V _{ISO}	5300	V _{RMS}
Creepage distance			≥ 7	mm
Clearance distance			≥ 7	mm
Isolation thickness between emitter and detector Comparative tracking index per DIN IEC 112/VDE 0303, part 1		CTI	≥ 175	
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω
	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω
Storage temperature range		T _{stg}	- 55 to + 150	°C
Ambient temperature range		T _{amb}	- 55 to + 100	°C
Soldering temperature (2)	max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm	T _{sld}	260	°C

Notes

(1) T_{amb} = 25 °C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

(2) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	I _F = 60 mA		V _F		1.25	1.65	V
Reverse current	V _R = 6.0 V		I _R		0.01	10	μA
Capacitance	V _R = 0 V, f = 1.0 MHz		C _O		13		pF
Thermal resistance			R _{thja}		750		K/W
OUTPUT							
Collector emitter capacitance	V _{CE} = 5.0 V, f = 1.0 MHz		C _{CCE}		5.2		pF
Thermal resistance			R _{thja}		500		K/W



SFH615AA/AGB/AGR/ABM/ABL/AY/AB

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ELECTRICAL CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
COUPLER							
Collector emitter saturation voltage	$I_F = 10 \text{ mA}$, $I_C = 2.5 \text{ mA}$		V_{CEsat}		0.25	0.4	V
Coupling capacitance			C_C		0.4		pF
Collector emitter leakage current	$V_{CEO} = 10 \text{ V}$	SFH615AA	I_{CEO}		10	100	nA
		SFH615AGB	I_{CEO}		10	100	nA
		SFH615AGR	I_{CEO}		10	100	nA
		SFH615ABM	I_{CEO}		10	100	nA
		SFH615ABL	I_{CEO}		10	100	nA
		SFH615AY	I_{CEO}		10	100	nA
		SFH615AB	I_{CEO}		10	100	nA

Note

$T_{amb} = 25 \text{ }^\circ\text{C}$, unless otherwise specified.

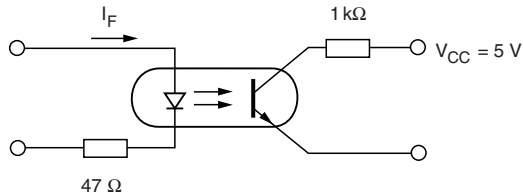
Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_C/I_F	$I_F = 5.0 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$	SFH615AA	CTR	50		600	%
		SFH615AGB	CTR	100		600	%
		SFH615AGR	CTR	100		300	%
		SFH615ABM	CTR	200		400	%
		SFH615ABL	CTR	200		600	%
		SFH615AY	CTR	50		150	%
		SFH615AB	CTR	80		260	%

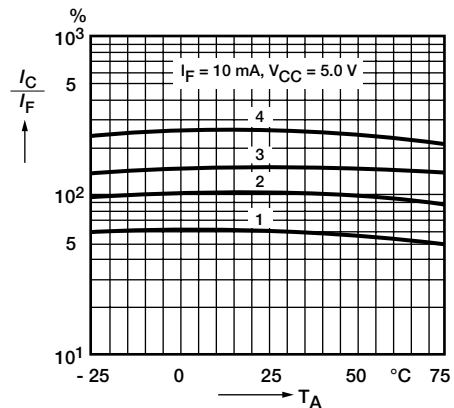
SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Turn-on time	$I_F = 5.0 \text{ mA}$	t_{on}		2.0		μs	
Turn-off time	$I_F = 5.0 \text{ mA}$	t_{off}		25		μs	

TYPICAL CHARACTERISTICS

$T_{amb} = 25 \text{ }^\circ\text{C}$, unless otherwise specified



isfh615aa_01



isfh615aa_02

Fig. 1 - Switching Operation (With Saturation)

Fig. 2 - Current Transfer Ratio (Typical) vs. Temperature

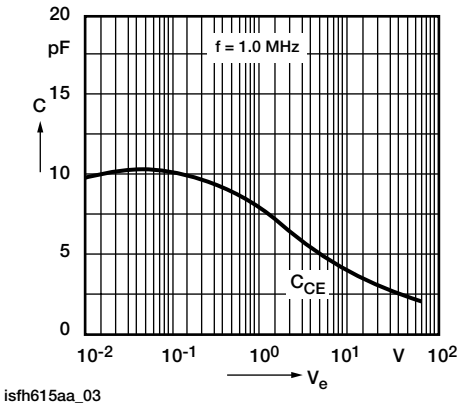


Fig. 3 - Transistor Capacitance (Typ.) vs. Collector Emitter Voltage

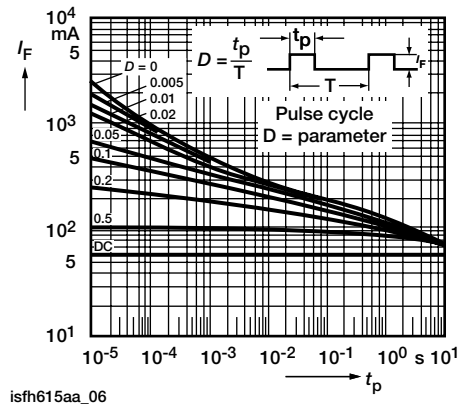


Fig. 6 - Permissible Pulse Handling Capability Forward Current vs. Pulse Width

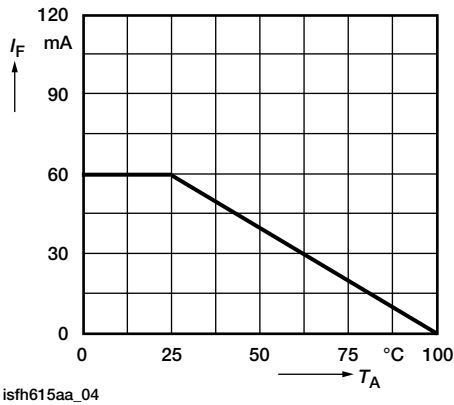


Fig. 4 - Permissible Diode Forward Current vs. Ambient Temperature

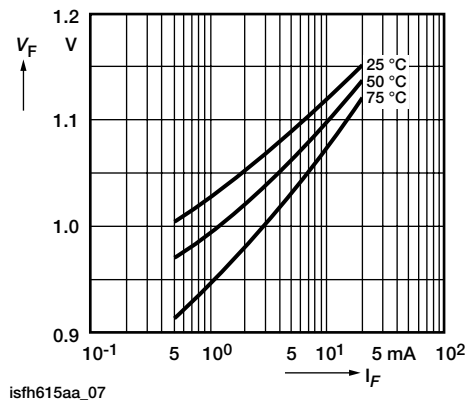


Fig. 7 - Diode Forward Voltage (Typ.) vs. Forward Current

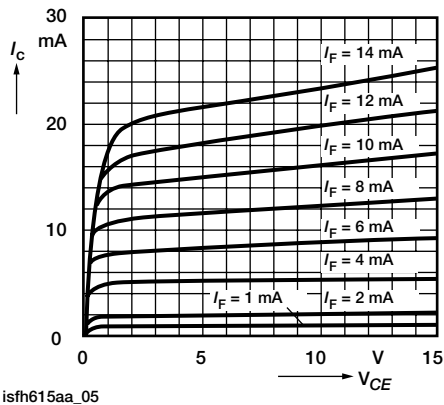


Fig. 5 - Output Characteristics (Typ.) Collector Current vs. Collector Emitter Voltage

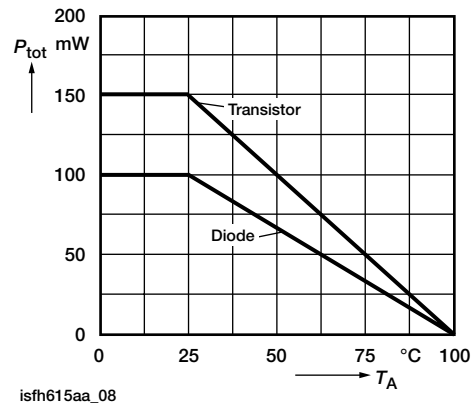


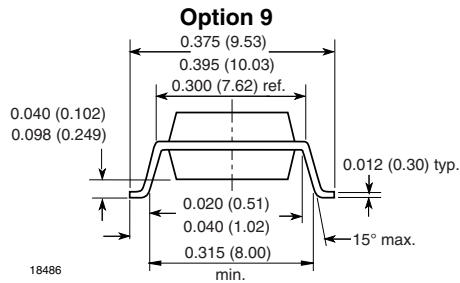
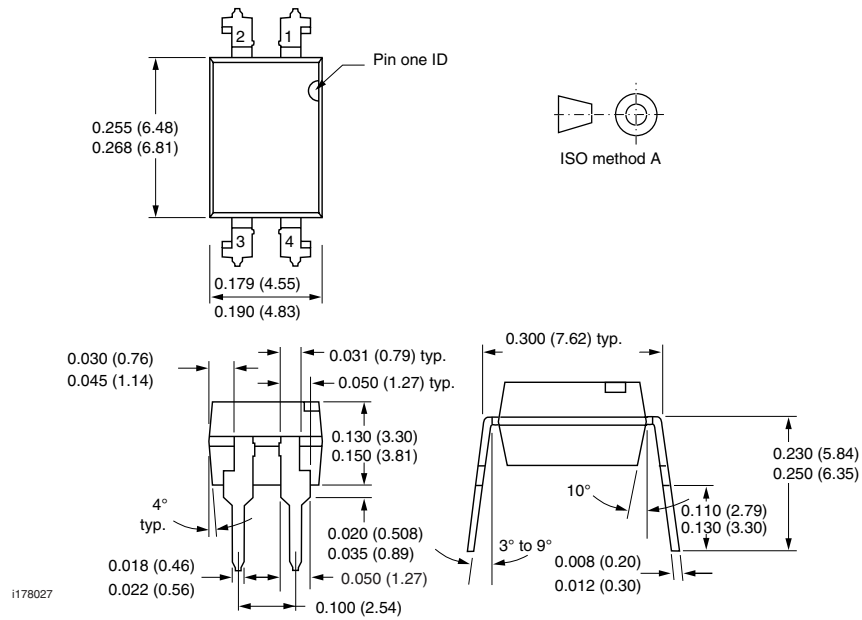
Fig. 8 - Permissible Power Dissipation vs. Temperature



SFH615AA/AGB/AGR/ABM/ABL/AY/AB

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High Reliability, 5300 V_{RMS}

PACKAGE DIMENSIONS in inches (millimeters)





OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
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- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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ВЧ соединители, коаксиальные кабели,
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: ocean@oceanchips.ru

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А